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ON Semiconductor®

August 2013

FOD3150A High Noise Immunity, 2.5 A Output Current, Gate Drive Optocoupler

Features

- High noise immunity characterized by 20 kV/μs minimum common mode rejection
- Use of P-channel MOSFETs at output stage enables output voltage swing close to the supply rail
- Wide supply voltage range from 15 V to 30 V
- Fast switching speed
 - 500 ns maximum propagation delay
 - 300 ns maximum pulse width distortion
- Under Voltage LockOut (UVLO) with hysteresis
- Extended industrial temperature range, -40°C to 100°C temperature range
- Safety and regulatory approvals
 - UL1577, 5000 V_{RMS} for 1 minute
 - DIN EN/IEC60747-5-2
- >8.0 mm clearance and creepage distance (option 'T')

Applications

- Industrial inverter
- Uninterruptible power supply
- Induction heating
- Isolated IGBT/Power MOSFET gate drive

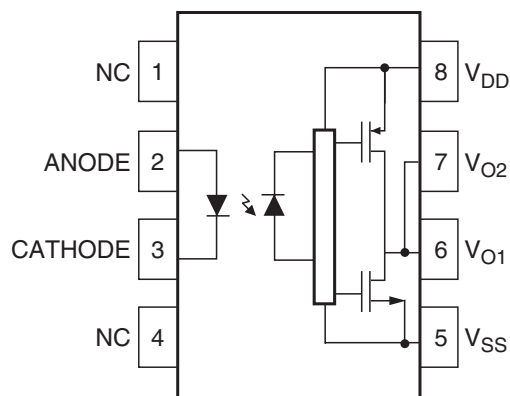
Description

The FOD3150A is a 2.5 A Output Current Gate Drive Optocoupler, capable of driving most 800 V / 20 A IGBTs or MOSFETs. It is ideally suited for fast switching driving of power IGBTs and MOSFETs used in motor control inverter applications, and high performance power system.

It utilizes Fairchild's patented coplanar packaging technology, Optoplanar®, and optimized IC design to achieve high noise immunity, characterized by high common mode rejection.

It consists of a gallium aluminum arsenide (AlGaAs) light emitting diode optically coupled to an integrated circuit with a high-speed driver for push-pull MOSFET output stage.

Functional Block Diagram



Note:

A 0.1μF bypass capacitor must be connected between pins 5 and 8.

Figure 1. Functional Block Diagram

Package Outlines

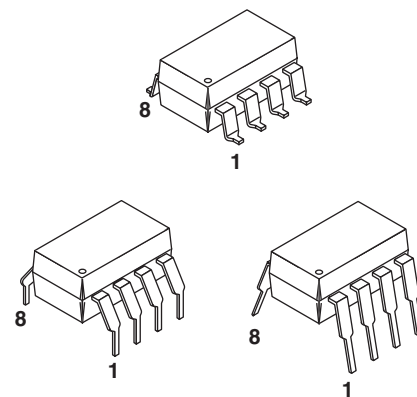


Figure 2. Package Outlines

FOD3150A — High Noise Immunity, 2.5 A Output Current, Gate Drive Optocoupler

Truth Table

LED	$V_{DD}-V_{SS}$ “Positive Going” (Turn-on)	$V_{DD}-V_{SS}$ “Negative Going” (Turn-off)	V_O
Off	0 V to 30 V	0 V to 30 V	Low
On	0 V to 11 V	0 V to 9.5 V	Low
On	11 V to 13.5 V	9.5 V to 12 V	Transition
On	13.5 V to 30 V	12 V to 30 V	High

Pin Definitions

Pin #	Name	Description
1	NC	Not Connected
2	Anode	LED Anode
3	Cathode	LED Cathode
4	NC	Not Connected
5	V_{SS}	Negative Supply Voltage
6	V_{O2}	Output Voltage 2 (internally connected to V_{O1})
7	V_{O1}	Output Voltage 1
8	V_{DD}	Positive Supply Voltage

Safety and Insulation Ratings

As per IEC 60747-5-2. This optocoupler is suitable for “safe electrical insulation” only within the safety limit data. Compliance with the safety ratings shall be ensured by means of protective circuits.

Symbol	Parameter	Min.	Typ.	Max.	Unit
	Installation Classifications per DIN VDE 0110/1.89 Table 1				
	For Rated Main Voltage < 150 Vrms		I-IV		
	For Rated Main Voltage < 300 Vrms		I-IV		
	For Rated Main Voltage < 450 Vrms		I-III		
	For Rated Main Voltage < 600 Vrms		I-III		
	Climatic Classification		55/100/21		
	Pollution Degree (DIN VDE 0110/1.89)		2		
CTI	Comparative Tracking Index	175			
V_{PR}	Input to Output Test Voltage, Method b, $V_{IORM} \times 1.875 = V_{PR}$, 100% Production Test with $t_m = 1$ second, Partial Discharge < 5 pC	1669			
	Input to Output Test Voltage, Method a, $V_{IORM} \times 1.5 = V_{PR}$, Type and Sample Test with $t_m = 60$ second, Partial Discharge < 5 pC	1335			
V_{IORM}	Max Working Insulation Voltage	890			V_{peak}
V_{IOTM}	Highest Allowable Over Voltage	6000			V_{peak}
	External Creepage	8			mm
	External Clearance	7.4			mm
	External Clearance (for Option T-0.4" Lead Spacing)	10.16			mm
	Insulation Thickness	0.5			mm
T_{Case}	Safety Limit Values – Maximum Values Allowed in the Event of a Failure				
	Case Temperature	150			°C
$I_{S,INPUT}$	Input Current	25			mA
$P_{S,OUTPUT}$	Output Power (Duty Factor $\leq 2.7\%$)	250			mW
R_{IO}	Insulation Resistance at T_S , $V_{IO} = 500$ V	10^9			Ω

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. $T_A = 25^\circ\text{C}$ unless otherwise specified.

Symbol	Parameter	Value	Units
T_{STG}	Storage Temperature	-55 to +125	$^\circ\text{C}$
T_{OPR}	Operating Temperature	-40 to +100	$^\circ\text{C}$
T_J	Junction Temperature	-40 to +125	$^\circ\text{C}$
T_{SOL}	Lead Wave Solder Temperature (refer to page 15 for reflow solder profile)	260 for 10sec	$^\circ\text{C}$
$I_{F(AVG)}$	Average Input Current	25	mA
V_R	Reverse Input Voltage	5	V
$I_{O(PEAK)}$	Peak Output Current ⁽¹⁾	3	A
$V_{DD} - V_{SS}$	Supply Voltage	0 to 35	V
$V_{O(PEAK)}$	Peak Output Voltage	0 to V_{DD}	V
$t_{R(IN)}, t_{F(IN)}$	Input Signal Rise and Fall Time	500	ns
PD_I	Input Power Dissipation ⁽²⁾⁽⁴⁾	45	mW
PD_O	Output Power Dissipation ⁽³⁾⁽⁴⁾	250	mW

Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to absolute maximum ratings.

Symbol	Parameter	Value	Units
T_A	Ambient Operating Temperature	-40 to +100	$^\circ\text{C}$
$V_{DD} - V_{SS}$	Power Supply	15 to 30	V
$I_{F(ON)}$	Input Current (ON)	7 to 16	mA
$V_{F(OFF)}$	Input Voltage (OFF)	0 to 0.8	V

Isolation Characteristics

Apply over all recommended conditions, typical value is measured at $T_A = 25^\circ\text{C}$

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Units
V_{ISO}	Input-Output Isolation Voltage	$T_A = 25^\circ\text{C}$, R.H. < 50 %, $t = 1.0$ minute, $I_{I-O} \leq 10 \mu\text{A}$, 50 Hz ⁽⁵⁾⁽⁶⁾	5000			V_{RMS}
R_{ISO}	Isolation Resistance	$V_{I-O} = 500 \text{ V}^{(5)}$		10^{11}		Ω
C_{ISO}	Isolation Capacitance	$V_{I-O} = 0 \text{ V}$, Frequency = 1.0 MHz ⁽⁵⁾		1		pF

Electrical Characteristics

Apply over all recommended conditions, typical value is measured at $V_{DD} = 30V$, $V_{SS} = \text{Ground}$, $T_A = 25^\circ\text{C}$ unless otherwise specified.

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Units
V_F	Input Forward Voltage	$I_F = 10 \text{ mA}$	1.2	1.5	1.8	V
$\Delta(V_F / T_A)$	Temperature Coefficient of Forward Voltage			-1.8		mV/°C
BV_R	Input Reverse Breakdown Voltage	$I_R = 10 \mu\text{A}$	5			V
C_{IN}	Input Capacitance	$f = 1 \text{ MHz}$, $V_F = 0 \text{ V}$		60		pF
I_{OH}	High Level Output Current ⁽¹⁾	$V_O = V_{DD} - 3 \text{ V}$	-1.0	-2.0	-2.5	A
		$V_O = V_{DD} - 6 \text{ V}$	-2.0		-2.5	
I_{OL}	Low Level Output Current ⁽¹⁾	$V_O = V_{SS} + 3 \text{ V}$	1.0	2.0	2.5	A
		$V_O = V_{SS} + 6 \text{ V}$	2.0		2.5	
V_{OH}	High Level Output Voltage	$I_F = 10 \text{ mA}$, $I_O = -2.5 \text{ A}$	$V_{DD} - 6.25 \text{ V}$	$V_{DD} - 2.5 \text{ V}$		V
		$I_F = 10 \text{ mA}$, $I_O = -100 \text{ mA}$	$V_{DD} - 0.25 \text{ V}$	$V_{DD} - 0.1 \text{ V}$		
V_{OL}	Low Level Output Voltage	$I_F = 0 \text{ mA}$, $I_O = 2.5 \text{ A}$		$V_{SS} + 2.5 \text{ V}$	$V_{SS} + 6.25 \text{ V}$	V
		$I_F = 0 \text{ mA}$, $I_O = 100 \text{ mA}$		$V_{SS} + 0.1 \text{ V}$	$V_{SS} + 0.25 \text{ V}$	
I_{DDH}	High Level Supply Current	$V_O = \text{Open}$, $I_F = 7 \text{ to } 16 \text{ mA}$		2.8	5	mA
I_{DDL}	Low Level Supply Current	$V_O = \text{Open}$, $V_F = 0 \text{ to } 0.8 \text{ V}$		2.8	5	mA
I_{FLH}	Threshold Input Current Low to High	$I_O = 0 \text{ mA}$, $V_O > 5 \text{ V}$		2.3	5.0	mA
V_{FHL}	Threshold Input Voltage High to Low	$I_O = 0 \text{ mA}$, $V_O < 5 \text{ V}$	0.8			V
V_{UVLO+}	Under Voltage Lockout Threshold	$I_F = 10 \text{ mA}$, $V_O > 5 \text{ V}$	11	12.7	13.5	V
V_{UVLO-}		$I_F = 10 \text{ mA}$, $V_O < 5 \text{ V}$	9.5	11.2	12.0	V
$UVLO_{HYS}$	Under Voltage Lockout Threshold Hysteresis			1.5		V

Switching Characteristics

Apply over all recommended conditions, typical value is measured at $V_{DD} = 30\text{ V}$, $V_{SS} = \text{Ground}$, $T_A = 25^\circ\text{C}$ unless otherwise specified.

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Units
t_{PHL}	Propagation Delay Time to Logic Low Output	$I_F = 7\text{ mA to }16\text{ mA}$, $R_g = 20\ \Omega$, $C_g = 10\text{ nF}$, $f = 10\text{ kHz}$, Duty Cycle = 50 %	100	275	500	ns
t_{PLH}	Propagation Delay Time to Logic High Output		100	255	500	ns
PWD	Pulse Width Distortion, $ t_{PHL} - t_{PLH} $			20	300	ns
PDD (Skew)	Propagation Delay Difference Between Any Two Parts or Channels, $(t_{PHL} - t_{PLH})^{(7)}$			-350	350	ns
t_r	Output Rise Time (10% – 90%)				60	ns
t_f	Output Fall Time (90% – 10%)				60	ns
$t_{UVLO\ ON}$	UVLO Turn On Delay		$I_F = 10\text{ mA}$, $V_O > 5\text{ V}$		1.6	
$t_{UVLO\ OFF}$	UVLO Turn Off Delay	$I_F = 10\text{ mA}$, $V_O < 5\text{ V}$		0.4		μs
$ CM_H $	Common Mode Transient Immunity at Output High	$T_A = 25^\circ\text{C}$, $V_{DD} = 30\text{ V}$, $I_F = 7\text{ to }16\text{ mA}$, $V_{CM} = 2000\text{ V}^{(8)}$	20	50		$\text{kV}/\mu\text{s}$
$ CM_L $	Common Mode Transient Immunity at Output Low	$T_A = 25^\circ\text{C}$, $V_{DD} = 30\text{ V}$, $V_F = 0\text{ V}$, $V_{CM} = 2000\text{ V}^{(9)}$	20	50		$\text{kV}/\mu\text{s}$

Notes:

- Maximum pulse width = $10\ \mu\text{s}$, maximum duty cycle = 1.1 %.
- Derate linearly above 87°C , free air temperature at a rate of $0.77\text{ mW}/^\circ\text{C}$.
- No derating required across temperature range.
- Functional operation under these conditions is not implied. Permanent damage may occur if the device is subjected to conditions outside these ratings.
- Device is considered a two terminal device: pins 2 and 3 are shorted together and pins 5, 6, 7 and 8 are shorted together.
- $5,000\text{ V}_{RMS}$ for 1 minute duration is equivalent to $6,000\text{ VAC}_{RMS}$ for 1 second duration.
- The difference between t_{PHL} and t_{PLH} between any two FOD3150A parts under same test conditions.
- Common mode transient immunity at output high is the maximum tolerable negative dV_{cm}/dt on the trailing edge of the common mode impulse signal, V_{cm} , to assure that the output will remain high (i.e., $V_O > 15.0\text{ V}$).
- Common mode transient immunity at output low is the maximum tolerable positive dV_{cm}/dt on the leading edge of the common pulse signal, V_{cm} , to assure that the output will remain low (i.e., $V_O < 1.0\text{ V}$).

Typical Performance Curves

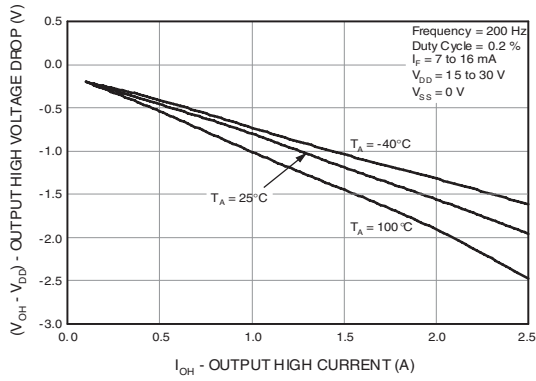


Figure 3. Output High Voltage Drop vs. Output High Current

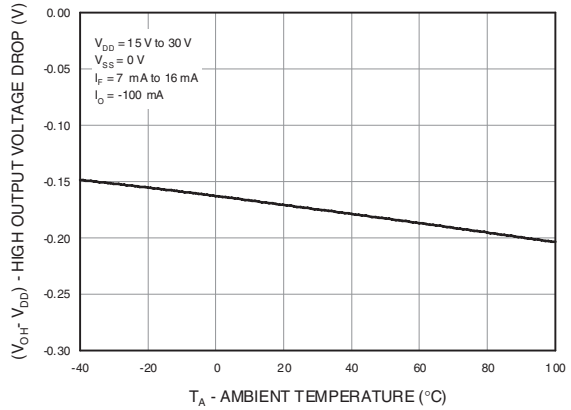


Figure 4. Output High Voltage Drop vs. Ambient Temperature

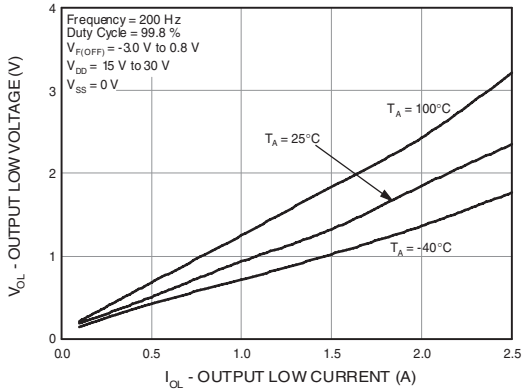


Figure 5. Output Low Voltage vs. Output Low Current

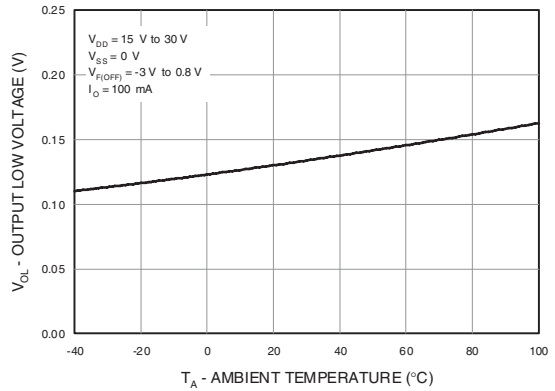


Figure 6. Output Low Voltage vs. Ambient Temperature

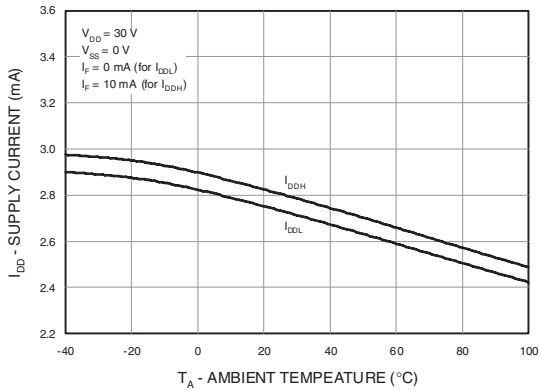


Figure 7. Supply Current vs. Ambient Temperature

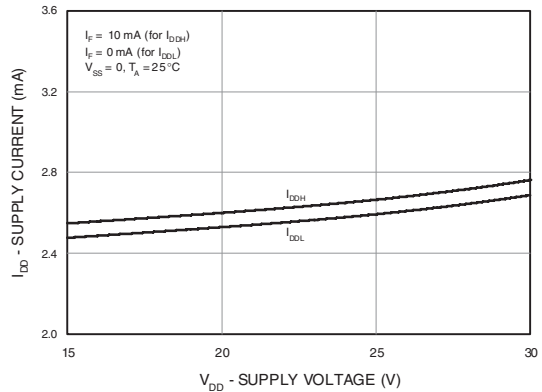


Figure 8. Supply Current vs. Supply Voltage

Typical Performance Curves (Continued)

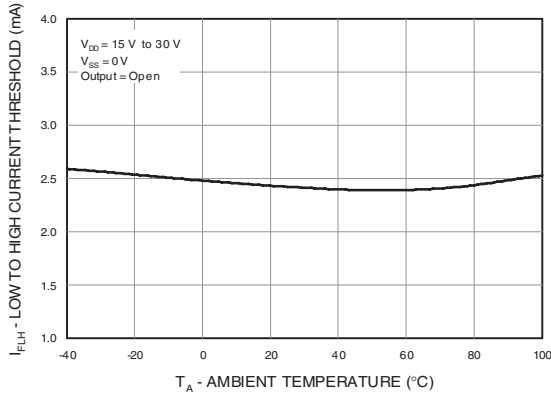


Figure 9. Low to High Input Current Threshold vs. Ambient Temperature

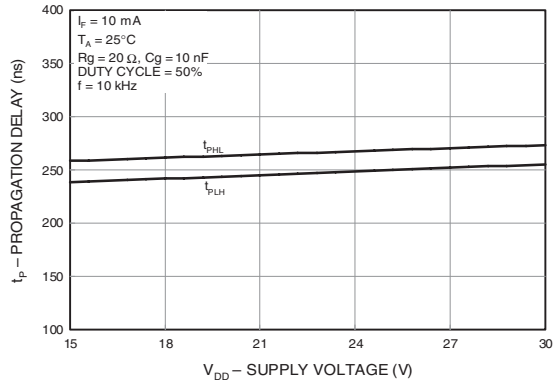


Figure 10. Propagation Delay vs. Supply Voltage

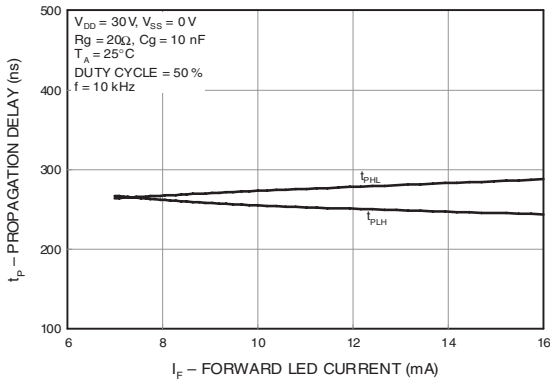


Figure 11. Propagation Delay vs. LED Forward Current

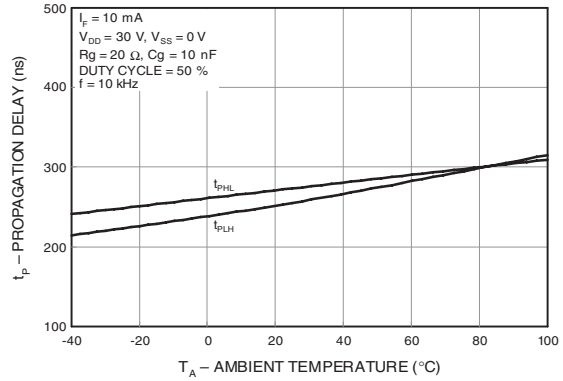


Figure 12. Propagation Delay vs. Ambient Temperature

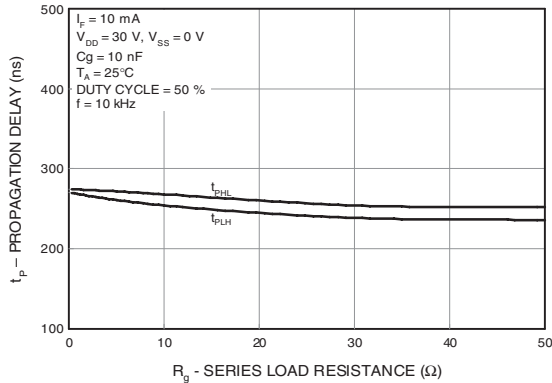


Figure 13. Propagation Delay vs. Series Load Resistance

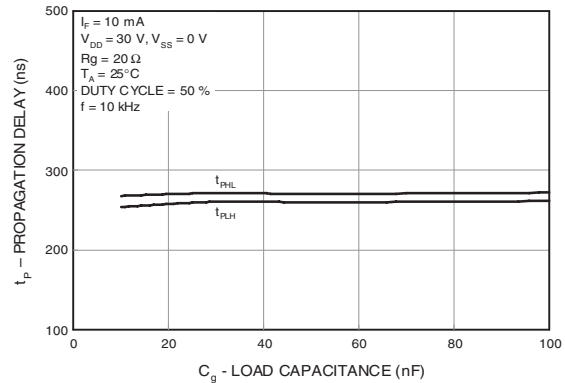


Figure 14. Propagation Delay vs. Load Capacitance

Typical Performance Curves (Continued)

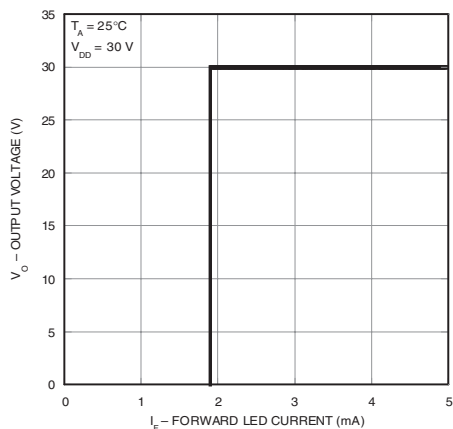


Figure 15. Transfer Characteristics

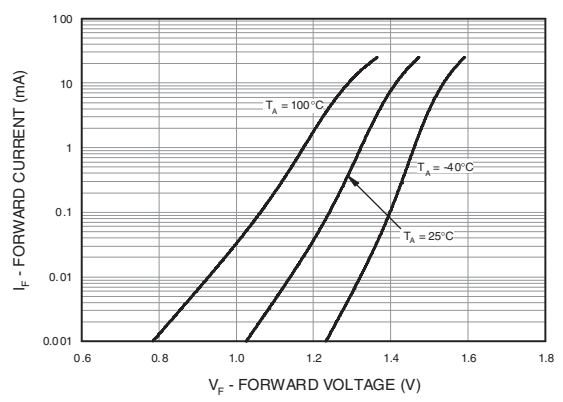


Figure 16. Input Forward Current vs. Forward Voltage

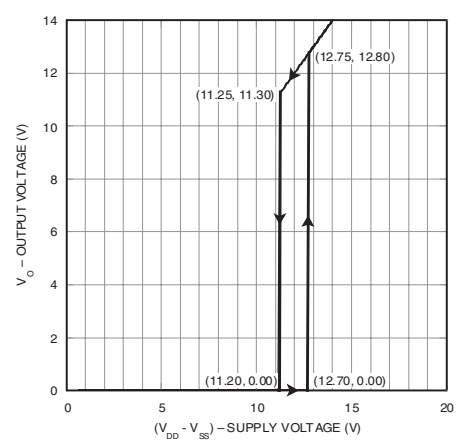


Figure 17. Under Voltage Lockout

Test Circuit

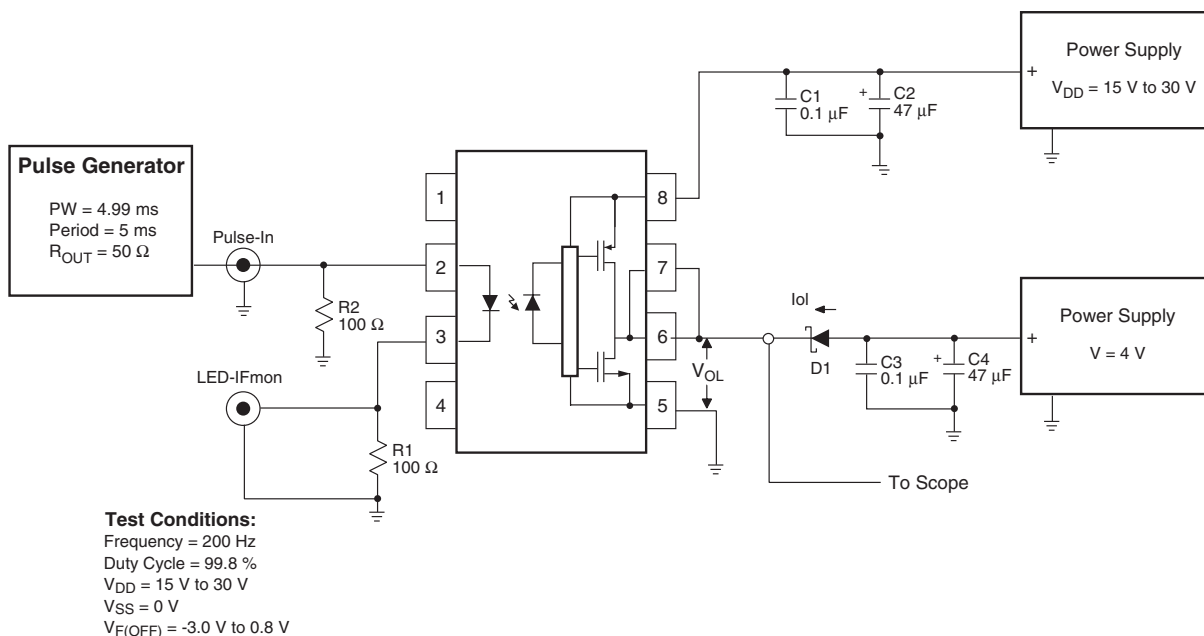


Figure 18. I_{OL} Test Circuit

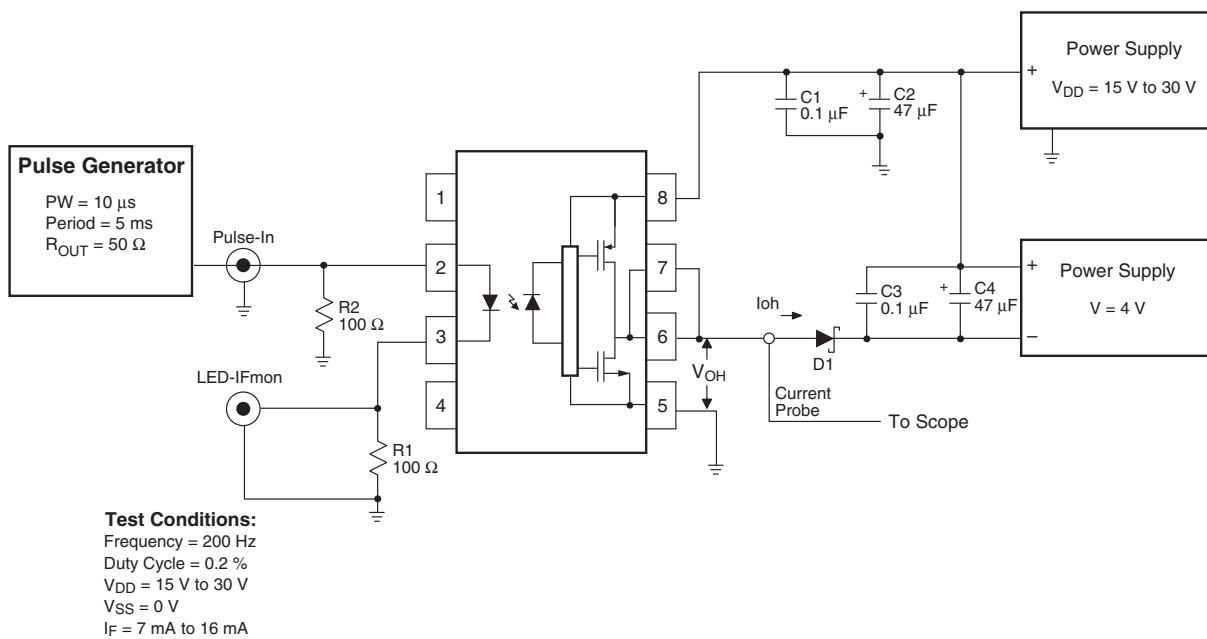


Figure 19. I_{OH} Test Circuit

Test Circuit (Continued)

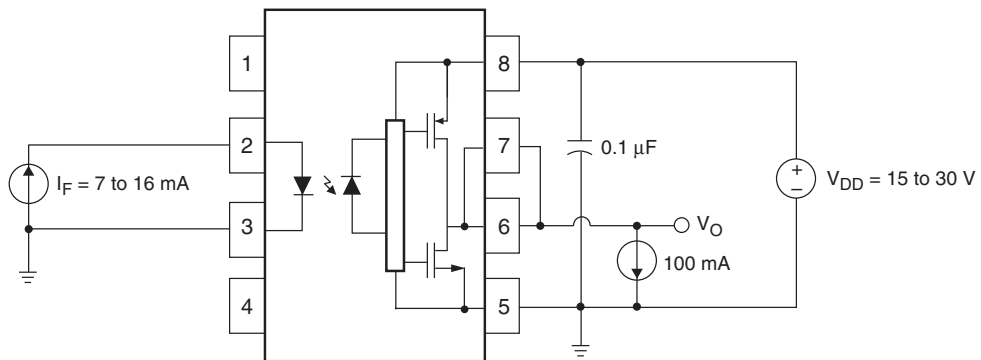


Figure 20. V_{OH} Test Circuit

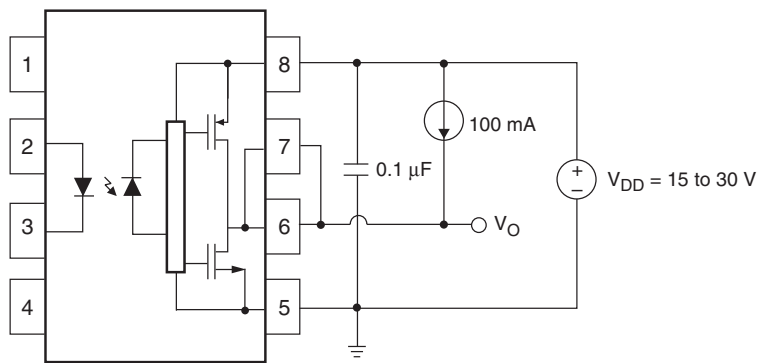


Figure 21. V_{OL} Test Circuit

Test Circuit (Continued)

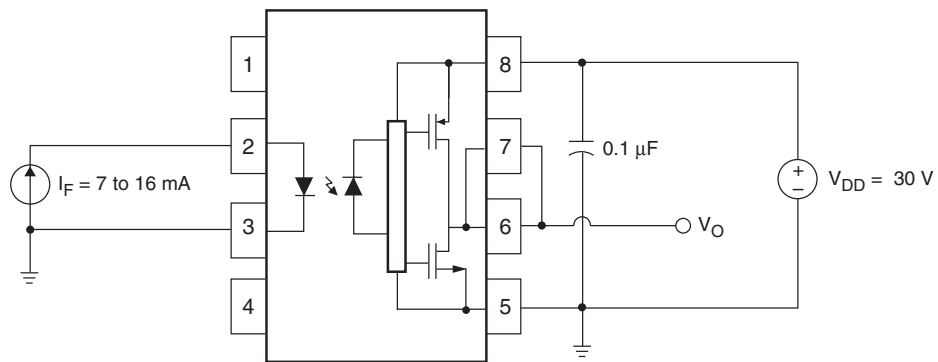


Figure 22. I_{DDH} Test Circuit

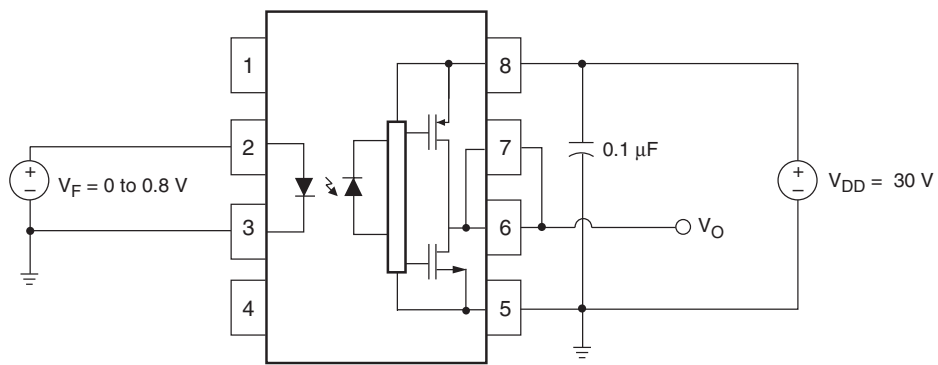


Figure 23. I_{DDL} Test Circuit

Test Circuit (Continued)

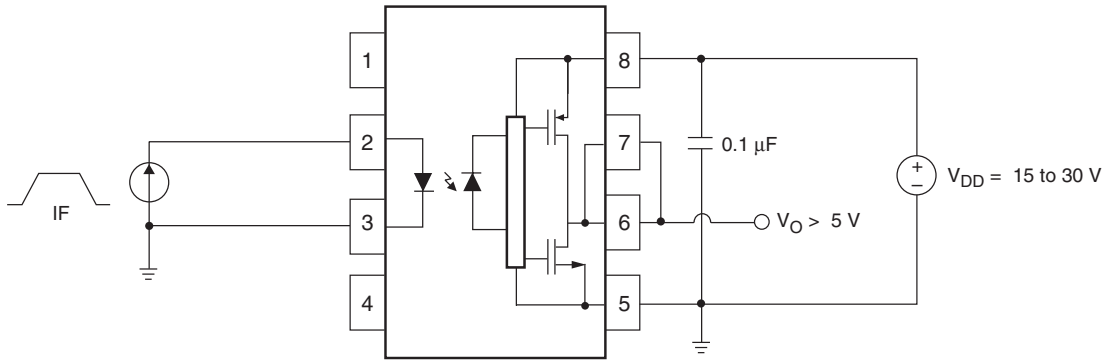


Figure 24. I_{FLH} Test Circuit

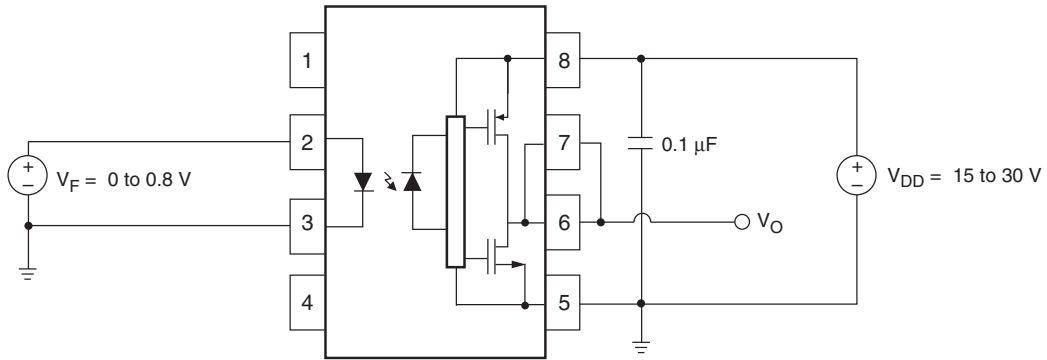


Figure 25. V_{FHL} Test Circuit

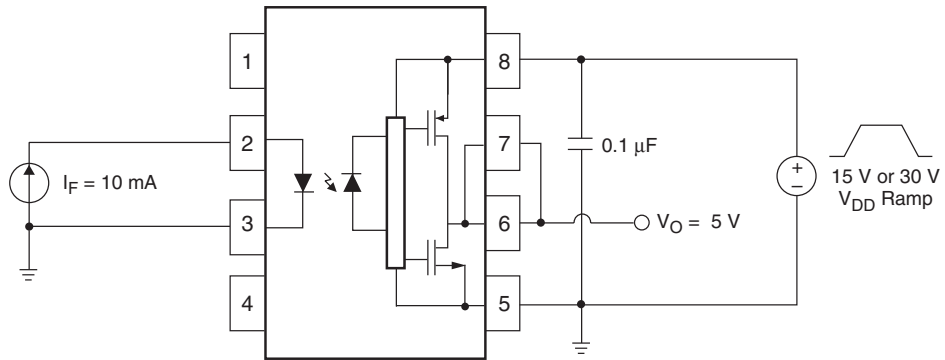


Figure 26. UVLO Test Circuit

Test Circuit (Continued)

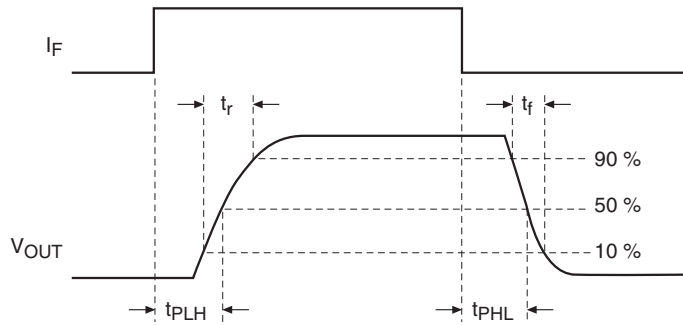
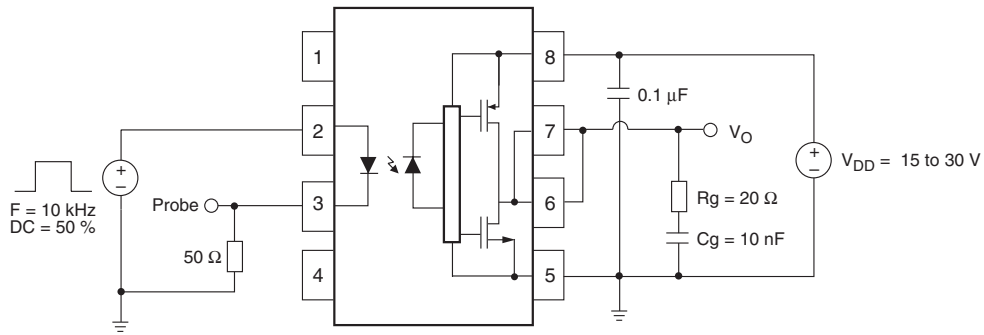


Figure 27. t_{pHL} , t_{pLH} , t_R and t_F Test Circuit and Waveforms

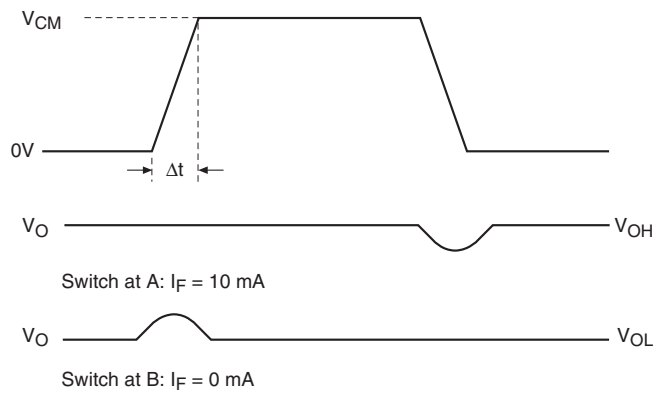
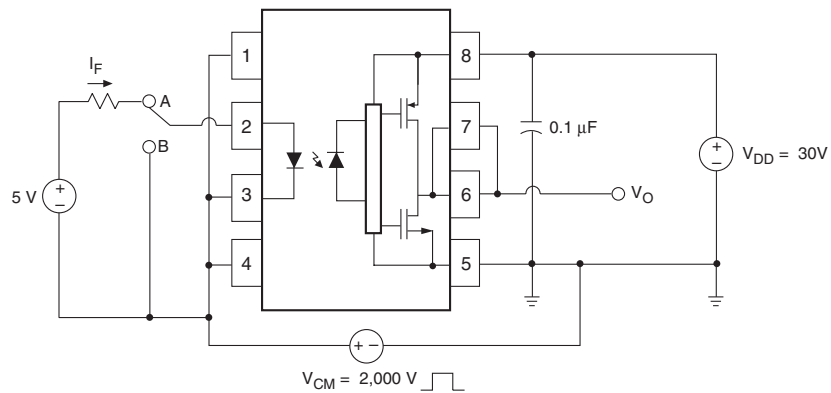
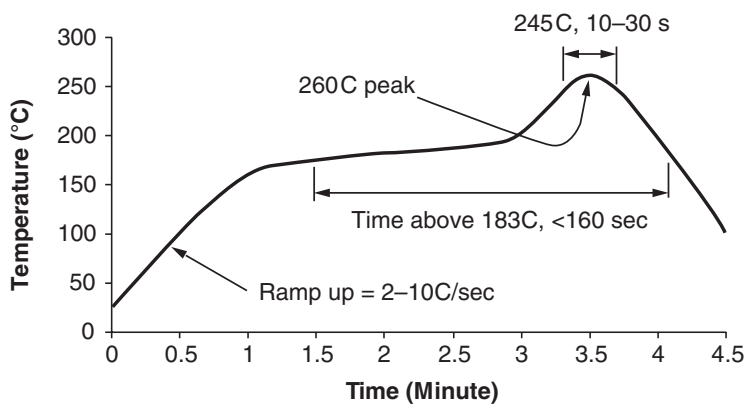


Figure 28. CMR Test Circuit and Waveforms

Reflow Profile



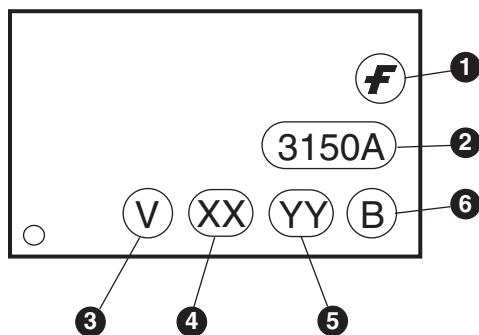
- Peak reflow temperature: 260C (package surface temperature)
- Time of temperature higher than 183C for 160 seconds or less
- One time soldering reflow is recommended

Figure 29. Reflow Profile

Ordering Information

Part Number	Package	Packing Method
FOD3150A	DIP 8-Pin	Tube (50 units per tube)
FOD3150AS	SMT 8-Pin (Lead Bend)	Tube (50 units per tube)
FOD3150ASD	SMT 8-Pin (Lead Bend)	Tape and Reel (1,000 units per reel)
FOD3150AV	DIP 8-Pin, IEC60747-5-2 option	Tube (50 units per tube)
FOD3150ASV	SMT 8-Pin (Lead Bend), DIN EN/IEC60747-5-2 option	Tube (50 units per tube)
FOD3150ASDV	SMT 8-Pin (Lead Bend), DIN EN/IEC60747-5-2 option	Tape and Reel (1,000 units per reel)
FOD3150AT	DIP 8-Pin, 0.4" Lead Spacing	Tube (50 units per tube)
FOD3150ATV	DIP 8-Pin, 0.4" Lead Spacing , DIN EN/IEC60747-5-2 option	Tube (50 units per tube)

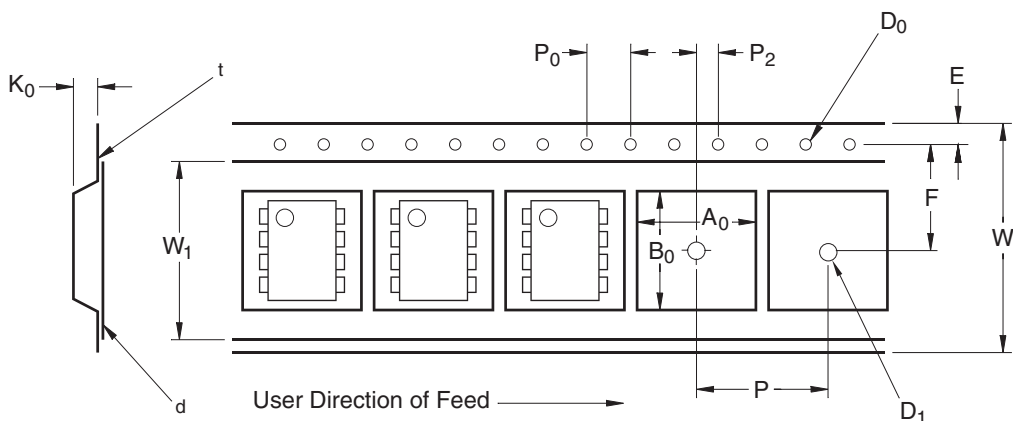
Marking Information



Definitions

1	Company logo
2	Device number
3	DIN EN/IEC60747-5-2 Option (only appears on component ordered with this option)
4	Two digit year code, e.g., '08'
5	Two digit work week ranging from '01' to '53'
6	Assembly package code

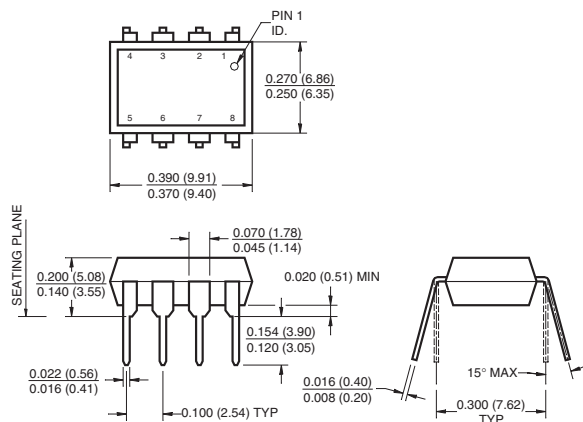
Carrier Tape Specifications



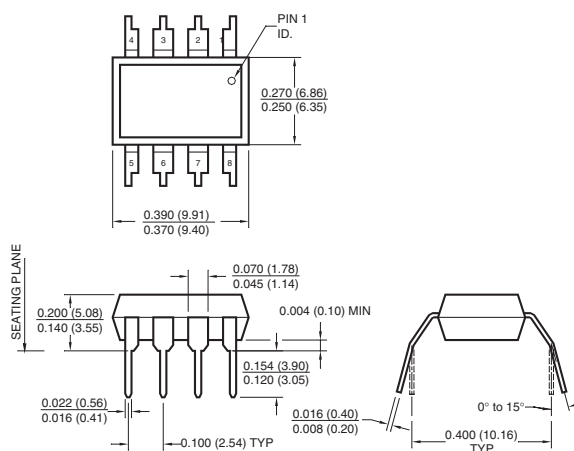
Symbol	Description	Dimension in mm
W	Tape Width	16.0 ± 0.3
t	Tape Thickness	0.30 ± 0.05
P_0	Sprocket Hole Pitch	4.0 ± 0.1
D_0	Sprocket Hole Diameter	1.55 ± 0.05
E	Sprocket Hole Location	1.75 ± 0.10
F	Pocket Location	7.5 ± 0.1
P_2		2.0 ± 0.1
P	Pocket Pitch	12.0 ± 0.1
A_0	Pocket Dimensions	10.30 ± 0.20
B_0		10.30 ± 0.20
K_0		4.90 ± 0.20
W_1	Cover Tape Width	13.2 ± 0.2
d	Cover Tape Thickness	0.1 max
	Max. Component Rotation or Tilt	10°
R	Min. Bending Radius	30

Package Dimensions

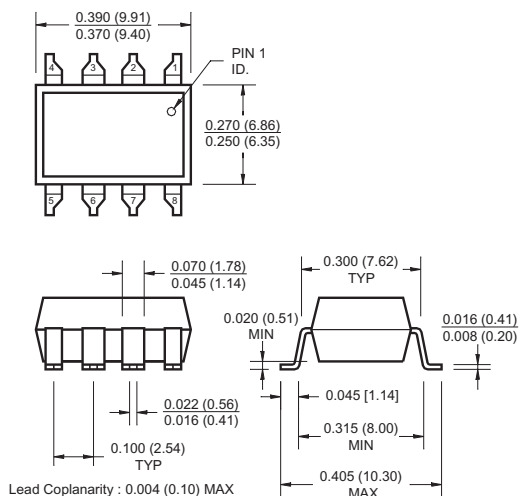
Through Hole



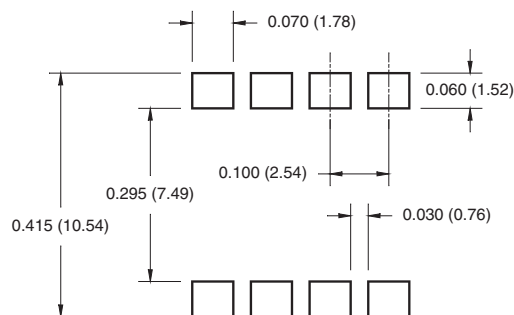
0.4" Lead Spacing



Surface Mount



8-Pin DIP – Land Pattern



Note:

All dimensions are in inches (millimeters)

Package drawings are provided as a service to customers considering Fairchild components. Drawings may change in any manner without notice. Please note the revision and/or date on the drawing and contact a Fairchild Semiconductor representative to verify or obtain the most recent revision. Package specifications do not expand the terms of Fairchild's worldwide terms and conditions, specifically the warranty therein, which covers Fairchild products.

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